



JLS05UGD5-3

1-Line Uni-directional High Power TVS Diode

Jialan-Microelectronics

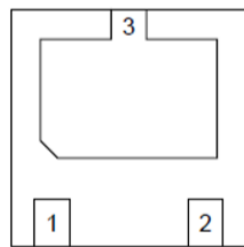
Description

The JLS05UGD5-3 is a high power TVS, utilizing leading monolithic silicon technology to provide fast response time and low ESD clamping voltage, making this device an ideal solution for protecting voltage sensitive lines. The JLS05UGD5-3 complies with the IEC 61000-4-2 (ESD) with $\pm 30\text{kV}$ air and $\pm 30\text{kV}$ contact discharge. It is assembled into a 3-pin DFN2020-3 lead-free package. The leads are finished with NiPdAu. Each device will protect one line. The combination of small size, and high surge capability makes them ideal for use in applications such as cellular phones, LCD displays, USB, and multi media card interfaces.

Circuit Diagram



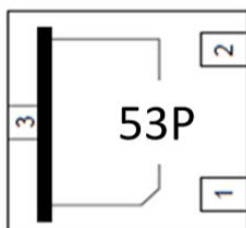
Circuit Diagram



Transparent top view

Pin Schematic

Marking Diagram



Transparent top view

53P:Device Marking Code

Features

- * 5800W peak pulse power (8/20 μs)
- * Low leakage: μA level
- * Operating voltage: 5V
- * Low clamping voltage
- * One power line protects
- * Complies with following standards:
 - IEC 61000-4-2 (ESD) immunity test
 - Air discharge: $\pm 30\text{kV}$
 - Contact discharge: $\pm 30\text{kV}$
 - IEC 61000-4-5 (Lightning) 280A (8/20 μs)
- * RoHS Compliant
- * Package: DFN2020-3

Applications

- * Power Management
- * Industrial Application
- * Power Supply Protection

Ordering Information

Part Number	Packaging	Reel Size
JLS05UGD5-3	3000/Tape & Reel	7 inch



JLS05UGD5-3

Absolute Maximum Ratings ($T_A=25^{\circ}\text{C}$ unless otherwise specified)

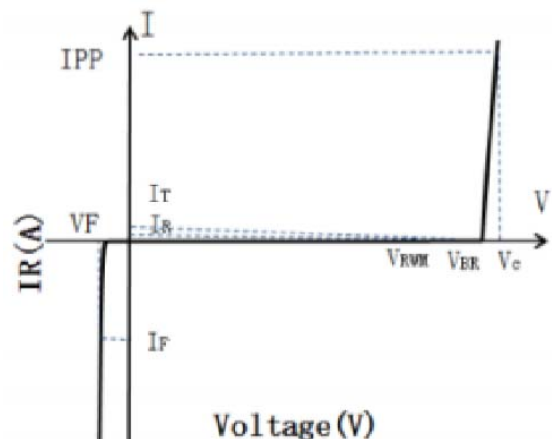
Parameter	Symbol	Value	Unit
Peak Pulse Power (8/20 μs)	Ppk	5800	W
Peak Pulse Current (8/20 μs)	IPP	280	A
ESD per IEC 61000-4-2 (Air)	VESD	± 30	kV
ESD per IEC 61000-4-2 (Contact)		± 30	
Operating Temperature Range	TJ	-55 to +125	$^{\circ}\text{C}$
Storage Temperature Range	Tstg	-55 to +150	$^{\circ}\text{C}$

Electrical Characteristics ($T_A=25^{\circ}\text{C}$ unless otherwise specified)

Parameter	Symbol	Test Condition	Min	Typ	Max	Unit
Reverse Working Voltage	V _{RWM}				5	V
Breakdown Voltage	V _{BR}	I _T = 1mA	6			V
Reverse Leakage Current	I _R	V _{RWM} = 5.0V			15	μA
Clamping Voltage	V _C	I _{PP} = 100A (8 x 20 μs pulse)			13	V
Clamping Voltage	V _C	I _{PP} = 280A (8 x 20 μs pulse)			21	V
Junction Capacitance	C _J	V _R = 0V, f = 1MHz		680		pF

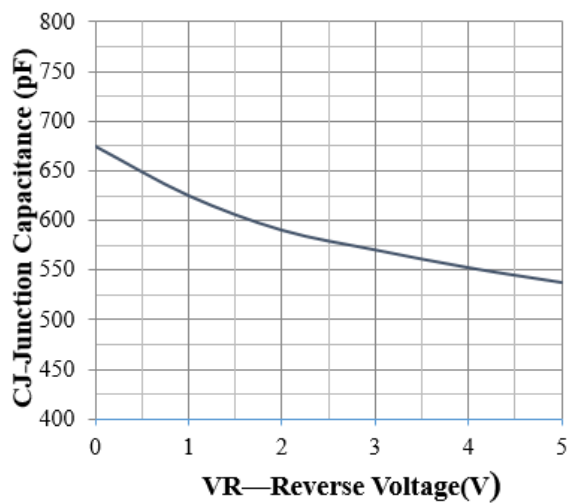
Portion Electronics Parameter

Symbol	Parameter
I _T	Test Current
I _{PP}	Maximum Reverse Peak Pulse Current
V _C	Clamping Voltage @I _C

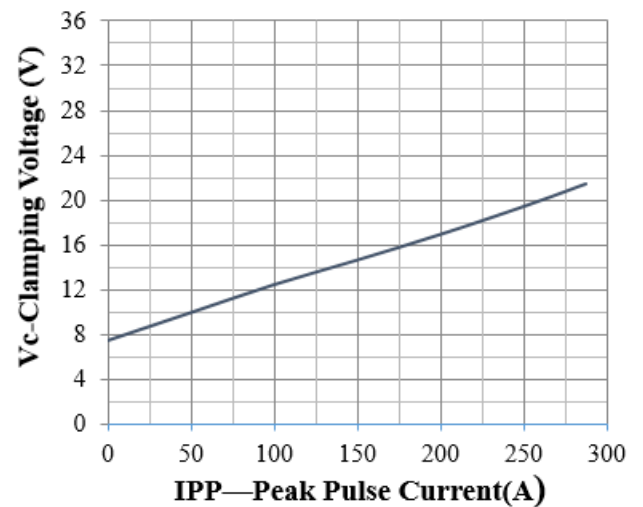




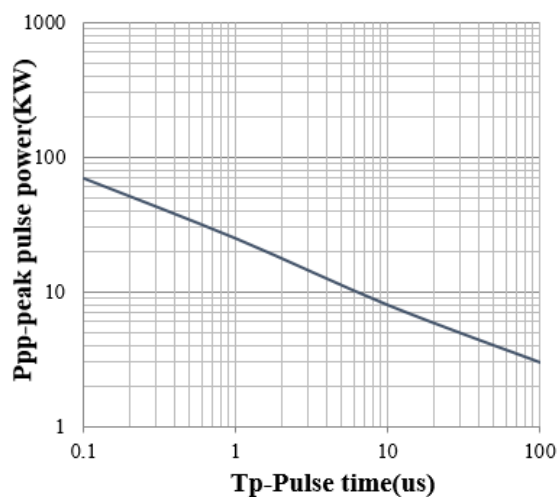
Typical Performance Characteristics ($T_A=25^{\circ}\text{C}$ unless otherwise Specified)



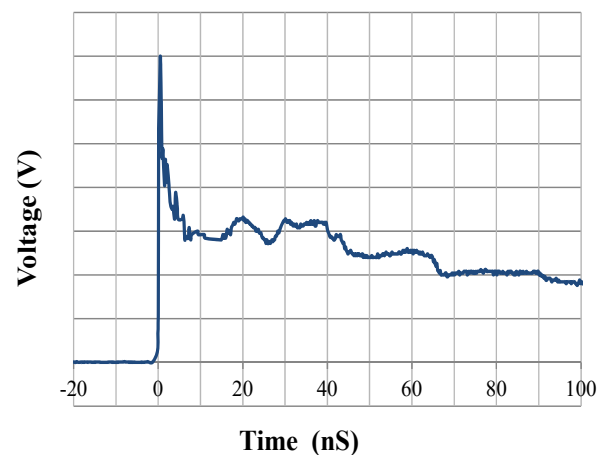
Junction Capacitance vs. Reverse Voltage



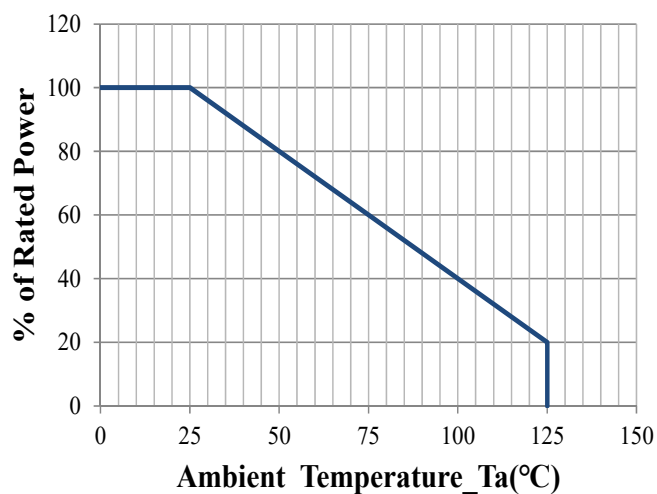
Clamping Voltage vs. Peak Pulse Current



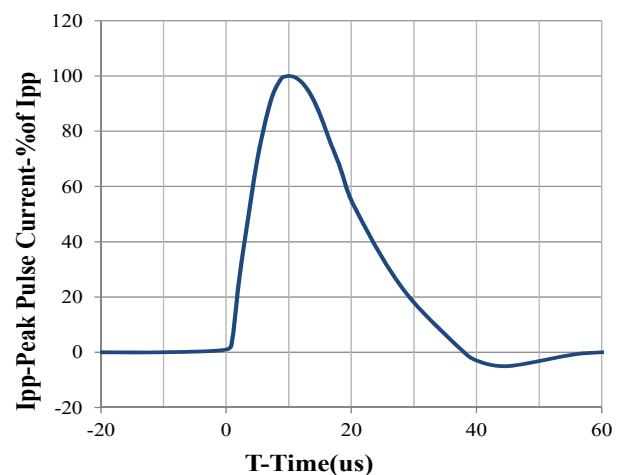
Peak Pulse Power vs. Pulse Time



IEC61000-4-2 Pulse Waveform



Power Derating Curve

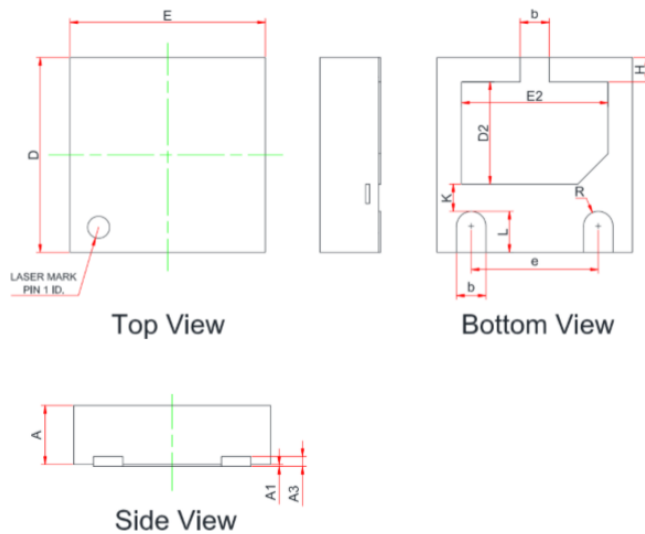


8 X 20us Pulse Waveform



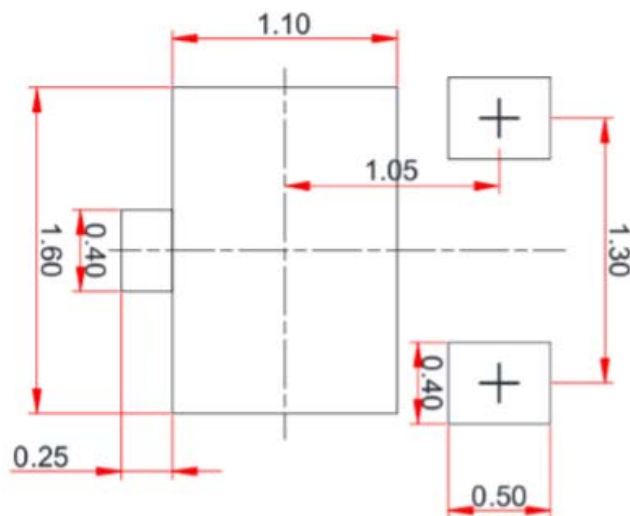
JLS05UGD5-3

DFN2020-3 Package Outline Drawing



SYM	MILLIMETERS		
	MIN	NOM	MAX
A	0.55	0.60	0.65
A1	0.00	0.02	0.05
A3	0.10REF.		
b	0.25	--	0.35
D	1.90	--	2.10
E	1.90	--	2.10
D2	0.95	--	1.15
E2	1.40	--	1.60
e	1.20		1.40
H	0.20	--	0.30
K	0.20		0.40
L	0.35	--	0.45
R	0.13	--	--

Suggested Land Pattern



NOTICE

Jelan-Link reserves the right to make changes without further notice to any products here in.

Only obligations are those in the Jelán-Link Standard Terms and Conditions of Sale and in no case will Jelán-Link be liable for any incidental, indirect, or consequential damages arising from the sale, resale, use, or misuse of its products.